PZT-PMN Ceramics for Large Displacement Piezoelectric Devices

Kee-Joe Lim and Jae-Yeol Park
School of Electrical and Computer Engineering, Chungbuk National University, Cheongju, Chungbuk 361-763, Korea

Jong-Sub Lee
R&D Center, EMD Co., Ltd. Ipiang Myun, Cheonan, Chungnam 363-792, Korea

Seong-Hwa Kang
Dept. of Industrial Safety Engineering, Chunchong College, Gangnae-myeon, Cheongwon-gun, Chungbuk 363-792, Korea

Hyun-Hoo Kim
Department of Electronics, Doowon College, Ansun, Gyeonggi 456-890, Korea

*E-mail: kjlim@chungbuk.ac.kr

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Piezoelectric and dielectric properties as functions of x and y mole ratio in yPb(ZrxTi1-x)O3(1-y)Pb(Mn0.33Nb0.67)O3 ceramics, PZT-PMN, are investigated for large displacement piezoelectric devices. From the experimental results, when y is 0.95 and x is 0.505, the piezoelectric and dielectric properties are maximum, that is, electromechanical coupling coefficient (kp), piezoelectric strain constant (d33), permittivity (e33/e0), and Curie temperature are 58 %, 272 pC/N, 1520 and about 350 °C, respectively. Also, when y is 0.90 and x is 0.50, their properties are 56 %, 242 pC/N, 1220, and 290 °C, respectively. As MgO dopant is added from 0 wt% to 1 wt%, kp increases to 63 % and Qm decreases to 500 at the MgO dopant of 0.1 wt%, and then kp decreases to 57 % as MgO is added.

Keywords: Piezoelectric ceramic, Large displacement, Dielectric properties

1. INTRODUCTION

As MEMS and smart material technologies mature, the mobile communication systems are becoming more attractive. In applications such as mobile phone and pager, the need and method to supply their energy can be a significant engineering problem. Mobile phone and pager have used batteries to supply their energy. Batteries offer only a limited life span to a system. In recent, the rapid developments in integrated circuit technology of the type described by Moore’s law have not been matched by similar advances in battery technology[1]. Thus, power requirements place important limits on the capability of mobile communication equipments. An alternative to batteries is to use the ambient energy that is available in the environment surrounding a system. Possible sources of the ambient energy include vibration, solar energy, and temperature difference, but the energy source using vibration may be in general. Accordingly, it is focused on micro generating system using piezoelectric ceramics. In order to apply to micro generating system, the important properties of piezoelectric ceramics for micro generating system are high electromechanical coupling coefficient, high piezoelectric strain constant and high permittivity. Piezoelectric ceramics that have these excellent piezoelectric and dielectric properties are lead zirconate titanate (PZT) based ternary piezoelectric ceramics. The ternary piezoelectric ceramics are used extensively for piezoelectric devices and are promising materials for large displacement actuator or electric generating devices. Compared with the binary solid solution ceramic system PZT, the ternary piezoelectric ceramics show desirable features[2,3]. In addition, the piezoelectric properties can be changed over a wide range by changing the composition and dopants[4-6].
PZT-PMN ceramic has higher piezoelectric activities and higher electro-mechanical coupling factor. It was well known that this ternary ceramic has high power characteristics.

In this paper, the piezoelectric and dielectric properties of Pb(ZrxTi1-x)O3Pb(Mn0.9Nb0.1)O3 ternary system are investigated for large displacement devices as functions of ZrTi mole ratio, ternary composition mole ration and dopant. Also, X-ray diffractometer(XRD) and scanning electron microscopy(SEM) analysis are measured to find MPB and crystallization of the film, and observed microstructure as a function of sintering temperature to obtain transition temperature. DTA(dielectric temperature analysis) is also measured.

2. EXPERIMENTAL

The composition formula of ternary piezoelectric ceramic system is designed as following:

\[ y\text{Pb(ZrxTi1-x)O}_3 (1-y)\text{Pb(Mn}_{0.9}\text{Nb}_{0.1})\text{O}_3 + z\text{[wt\%]}\text{MgO} \]

where, \(0.49 < x < 0.515, y = 0.9, 0.95, z = 0 \sim 1 \text{ wt\%} \)

The raw materials such as PbO, ZrO2, TiO2, MnCO3, Nb2O5 and MgO of 99 \% purity were used for the given composition of the films. After these powders were weighed in appropriate proportions and mixed, they were calcined at 800 °C for 4 h in a magnesia-covered crucible. The calcined products were crushed and then ground by ball milling for 48 h. The ground powder had a particle size ranging from 0.06 to 0.2 m with mean diameter of 0.15 m. The ground powder was mixed with organic binder, and the granule was pressed. TGA(thermal gravitation analysis) is measured to determine the burn-out temperature of binder[7].

Figure 1 shows a result of the measured TGA. As the temperature increases, its gravitation critically decreases because water and organic binder contained in it are evaporated. Therefore, the pressed body was kept at 450 °C for 6 h to burn out the organic binder, and then was sintered in a magnesia-covered crucible from 1100 °C to 1250 °C for 2 h in PbO atmosphere. The samples were metallized by printing Ag paste and firing at 590 °C and the specimens were poled under the electric field of 2.5 kV/mm for 30 min. in silicon oil of 120 °C

Piezoelectric strain constant(d33) is measured by Berlincourt d33-meter(CHANNEL product), and other dielectric and piezoelectric constants are measured by impedance analyzer (HP4194A) and calculated using resonance-antiresonance method by IRE Standard. The crystal structure was analyzed by X-ray diffraction pattern in the range of 2θ using Cu-Kα(λ=5.406 °C) (SCINTAG product).

Fig. 1. Thermal gravitation analysis.

3. RESULTS AND DISCUSSION

3.1 Micro structure observed by SEM

Figure 2 shows the photographs of micro-structure with the sintering temperature by SEM. As shown in Fig. 2, the grain is not completely grown at 1100 °C. As the sintering temperature increases, the grain size becomes large as well as the pores also increase gradually. Accordingly, from Fig. 2, optimal sintering temperature is 1150 °C in these piezoelectric ceramics.
Fig. 2. The micro structure of ceramic specimen according to sintering temperature.

3.2 Phase analysis by XRD
The typical XRD patterns of 0.95Pb(ZrxTi1-x)O3-0.05Pb(Mn1/3Nb2/3)O3 piezoelectric ceramics sintered at 1150 °C as a function of x are shown in Fig. 3.

Fig. 3. XRD patterns as a function of x in 0.95Pb(ZrxTi1-x)O3-0.05Pb(Mn1/3Nb2/3)O3 ceramics.

Fig. 4. XRD patterns as a function of x in 0.9Pb (ZrxTi1-x)O3-0.1Pb(Mn1/3Nb2/3)O3 ceramics.

The figure shows the typical perovskite phase of PZT-PMN film without secondary phase such as a pyrochlore phase. It also indicates that x≤0.50 results in tetragonal phase. On the other hand, rhombohedral phase is dominant at x>0.51 as revealed by disappearance of the splitting of the (200) and (211) peaks.

In this ternary system, the morphotropic phase boundary (MPB) assumes to be x=0.505, which coexists both ferroelectric phases. The XRD patterns of 0.9Pb(ZrxTi1-x)O3-0.1Pb (Mn1/3Nb2/3)O3 ceramics are shown in Fig. 4. From these results, the MPB assumes to be x=0.50. Comparing with pure PZT, it seems that the MPB of PZT-PMN ceramics shifts slightly to Ti-rich composition.

3.3 Piezoelectric and dielectric properties
The changes of electromechanical coupling coefficient (kp), piezoelectric strain constant(d33), mechanical quality factor(Qm) and permittivity (e337/ε0)[8] as functions of x and y in yPb(ZrxTi1-x)O3(1-y)Pb(Mn1/3 Nb2/3)O3 ceramics are shown in Fig. 5 to 8.

As shown in Figs. 5, 6 and 8, these factors increase gradually to maximum point with the increasing x mole ratio, and then decrease after the maximum point. When y is 0.95 and x is 0.505, each maximum value of kp, d33, and e337/ε0 is 58 %, 272 pC/N, and 1520, respectively. Also, when y is 0.90 and x is 0.50, each kp, d33 and e337/ε0 value is 56 %, 248 pC/N, and 1140, respectively.

From Fig. 7, a minimum value of mechanical quality factor is 1550 at y=0.05 and x=0.505, and 1820 at y=0.1 and x=0.50, respectively. From these results, when y is 0.95 and x is 0.505 or y is 0.90 and x is 0.50, the MPB is appeared in PZT-PMN ternary piezoelectric ceramic system, and is shifted to Ti-rich, compared with the MPB in pure PZT, which is generally known. As mole ratio of
ternary composition increases, the piezoelectric and dielectric properties decrease. Accordingly, in order to apply to large displacement devices, 0.95Pb(Zr0.505 Ti0.495)O3-0.05Pb(Mn1/3Nb2/3)O3 ceramic system is available.

![Graph](image1)

Fig. 5. Changes of \( k_p \) as a function of x mole.

![Graph](image2)

Fig. 6. The changes of \( d_{33} \) as a function of x mole.

![Graph](image3)

Fig. 7. The change of \( Q_m \) as a function of x mole.

![Graph](image4)

Fig. 8. The changes of \( \varepsilon_{33}^{T}/\varepsilon_0 \) as a function of x mole.

Figure 9 shows the relation between permittivity and temperature, which is measured by DTA. It indicates that Curie temperature may be around 350 °C for y of 0.95 and 290 °C for y of 0.9, respectively.

![Graph](image5)

Fig. 9. Phase transition temperature.

### 3.4 Dopant effect

The profiles of kp and Qm as a function of the amount of MgO added in the ternary composition of 0.95Pb(Zr0.505 Ti0.495)O3-0.05Pb(Mn1/3Nb2/3)O3 are shown in Fig. 10. The amount range of MgO is from 0 to 1 wt%. When the amount of MgO is 0.1 wt%, kp increases to 63 %, but Qm decreases to 500. As the amount of MgO increases to 1 wt%, kp decreases gradually and, however, Qm increases as shown in the figure.

Chen, et al.[9] reported that the positive ion of dopant reacted with Pb\(^{2+}\) ion and then the dopant made the stable pyrochlore phase. As a result, the grain size becomes small. It is believed that the Mg\(^{2+}\) ions are substituted to B-site rather than A-site in the perovskite lattice at MgO dopant of 0.1 wt%, resulting in the generation of oxygen vacancies in the structure. The oxygen vacancies directly contribute to the shrinkage of the lattice and the dielectric properties are lowered.
However, as the grain size becomes small with increasing dopants after 0.1 wt%, the electromechanical coupling coefficient lowers and mechanical quality factor increases.

Fig. 10. The changes of kp and Qm as a function of the amount of MgO.

4. CONCLUSIONS

In summary, the piezoelectric and dielectric properties as functions of x and y in yPb(ZrxTi1-x)O3(1-y)Pb(Mn1/3Nb2/3)O3 piezoelectric ceramics are studied for large displacement devices. When y is 0.95 and x is 0.505, the piezoelectric and dielectric properties of the ternary piezoelectric ceramic have the best values as follows: electromechanical coupling coefficient(kp), piezoelectric strain constant(d33), permittivity(ε33/ε0), and Curie temperature are 58 %, 272 pC/N, 1520 and about 350 °C, respectively. Also, when y is 0.9 and x is 0.50, its properties, kp, d33, ε33/ε0, and Curie temperature are 56 %, 248 pC/N, 1140, 290 °C, respectively.

Also, as MgO is added from 0 wt% to 1 wt%, kp increases to 63 % and Qm decreases to 500 at 0.1 wt% MgO, and then kp decreases, and Qm increases slightly until 1 wt% of MgO. The superior properties in 0.95Pb(Zr0.505Ti0.495)O3-0.05Pb(Mn1/3Nb2/3)O3 0.1 wt% MgO ceramic is shown. It is concluded that this piezoelectric ceramic can be a useful material for large displacement piezoelectric devices.

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